

S-Parameter of a Thin-Film BAW Resonator

Introduction

This model shows how to compute the S-parameter for a piezoelectric MEMS device by extending the tutorial Thin-Film BAW Composite Resonator. The measurement of Sparameter is commonly used to characterize such devices for RF applications. The terminal feature in the Electrostatics physics interface provides straightforward access to the computed S-parameters for frequency domain study types.

See the PDF documentation for the tutorial Thin-Film BAW Composite Resonator (thin_film_baw_resonator.mph) for a general discussion on BAW resonators and for the specific device structure that the model is based on.

Model Definition

A new Terminal boundary condition and a new Frequency Domain study are added to the original model to use the built-in functionality of the software to compute the Sparameter.

Results and Discussion

Figure 1 and Figure 2 shows the real and imaginary parts of the computed S-parameter and the S-parameter in dB scale, respectively. Figure 1 also shows the S-parameter computed from the admittance, which matches exactly as the values computed by the new Terminal boundary condition, as one would expect.

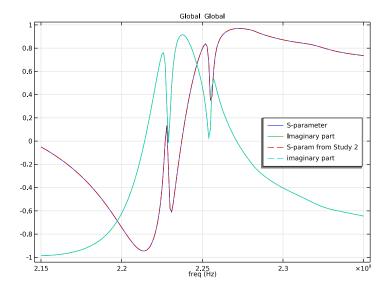


Figure 1: The real and imaginary parts of the S-parameter.

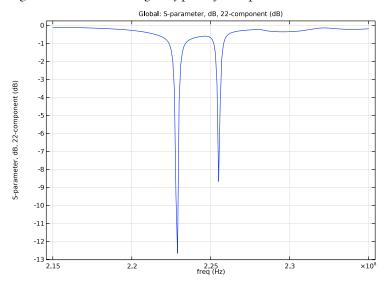


Figure 2: The S-parameter in dB scale.

1. See the PDF documentation for the original tutorial under MEMS_Module/Piezoelectric_Devices/thin_film_baw_resonator.

Application Library path: MEMS_Module/Piezoelectric_Devices/thin_film_baw_resonator_s_parameter

Modeling Instructions

ROOT

Open the tutorial model Thin-Film BAW Composite Resonator (filename: thin_film_baw_resonator.mph).

APPLICATION LIBRARIES

- I From the File menu, choose Application Libraries.
- 2 In the Application Libraries window, select MEMS Module>Piezoelectric Devices> thin_film_baw_resonator in the tree.
- 3 Click Open.

Duplicate the existing **Terminal** boundary condition and change the type to **Terminated** for the software to compute the S-parameter automatically. Note that the terminal number automatically increments from 1 to 2. The terminal number will be used later when accessing built-in global variables for the terminal. Set the power to a reasonable number.

COMPONENT I (COMPI)

In the Model Builder window, expand the Component I (compl) node.

ELECTROSTATICS (ES)

Terminal 2

- I In the Model Builder window, expand the Component I (compl)>Electrostatics (es) node.
- 2 Right-click Component I (compl)>Electrostatics (es)>Terminal I and choose Duplicate.
- 3 In the Settings window for Terminal, locate the Terminal section.
- 4 From the Terminal type list, choose Terminated.
- **5** In the P_0 text field, type 0.1.

Disable the new boundary condition in the previous studies to preserve their original setup, so that if a previous study is computed again the result will not be affected.

STUDY I

Steb 1: Eigenfrequency

- I In the Model Builder window, expand the Study I node, then click Step I: Eigenfrequency.
- 2 In the Settings window for Eigenfrequency, locate the Physics and Variables Selection section.
- 3 Select the Modify model configuration for study step check box.
- 4 In the tree, select Component I (compl)>Electrostatics (es)>Terminal 2.
- 5 Click O Disable.

STUDY 2

Step 1: Frequency Domain

- I In the Model Builder window, expand the Study 2 node, then click Step 1: Frequency Domain.
- 2 In the Settings window for Frequency Domain, locate the Physics and Variables Selection section.
- 3 Select the Modify model configuration for study step check box.
- 4 In the tree, select Component I (compl)>Electrostatics (es)>Terminal 2.
- 5 Click ODisable.

Now create a new study to use the new terminal boundary condition for S-parameter calculation. Start with an empty study and then copy and paste the Frequency Domain study step from Study 2. Clear the Modify model configuration for study step check box before clicking Compute.

ADD STUDY

- I In the Home toolbar, click Add Study to open the Add Study window.
- 2 Go to the Add Study window.
- 3 Find the Studies subsection. In the Select Study tree, select Empty Study.
- 4 Click Add Study in the window toolbar.
- 5 In the Home toolbar, click Add Study to close the Add Study window.

STUDY 2

Step 1: Frequency Domain

Right-click Step 1: Frequency Domain and choose Copy.

STUDY 3

In the Model Builder window, right-click Study 3 and choose Paste Frequency Domain.

Step 1: Frequency Domain

- I In the Settings window for Frequency Domain, locate the Physics and Variables Selection section.
- 2 Clear the Modify model configuration for study step check box.
- 3 In the Home toolbar, click **Compute**.

RESULTS

Stress (solid)

Create a 1D plot group to plot the S-parameter as a function of the frequency. By default the real part of the expression is plotted. To plot the imaginary part, use the imag() function.

S-barameter

- I In the Home toolbar, click Add Plot Group and choose ID Plot Group.
- 2 In the Settings window for ID Plot Group, type S-parameter in the Label text field.
- 3 Locate the Data section. From the Dataset list, choose Study 3/Solution 3 (sol3).

Global I

- I Right-click **S-parameter** and choose **Global**.
- 2 In the Settings window for Global, locate the y-Axis Data section.
- **3** In the table, enter the following settings:

Expression	Unit	Description
es.S22	1	S-parameter
imag(es.S22)	1	Imaginary part

The S-parameter can also be calculated using the admittance from Study 2. By default the reference impedance is 50 Ohm, which can be customized under the section Manual **Terminal Sweep Settings** in the Settings window for the **Electrostatics** main physics node. Here we have left it as the default value, so we will use the formula (1-es.Y11*50[ohm])/

(1+es.Y11*50[ohm]) to define the S-parameter. Use **Update Solution** to make the variable definition available to the solution of Study 2 without solving it again.

DEFINITIONS

Variables 1

- I In the Model Builder window, under Component I (compl) right-click Definitions and choose Variables.
- 2 In the Settings window for Variables, locate the Variables section.
- **3** In the table, enter the following settings:

Name	Expression	Unit	Description
S11	(1-es.Y11*50[ohm])/ (1+ es.Y11*50[ohm])		S-param from Study 2

STUDY 2

In the Study toolbar, click C Update Solution.

RESULTS

Global 2

- I In the Model Builder window, right-click S-parameter and choose Global.
- 2 In the Settings window for Global, locate the Data section.
- 3 From the Dataset list, choose Study 2/Solution 2 (sol2).
- 4 Locate the y-Axis Data section. In the table, enter the following settings:

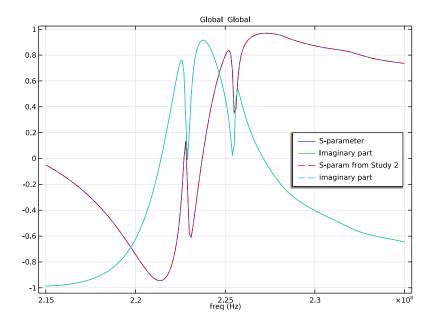
Expression	Unit	Description
S11	1	S-param from Study 2
imag(S11)	1	imaginary part

5 Click to expand the Coloring and Style section. Find the Line style subsection. From the Line list, choose Dashed.

S-barameter

- I In the Model Builder window, click S-parameter.
- 2 In the Settings window for ID Plot Group, locate the Legend section.
- 3 From the Position list, choose Middle right.

4 In the S-parameter toolbar, click Plot.



Both the real and the imaginary part of the S-parameter matches exactly between the two studies, as one would expect. The S-parameter in dB scale is also available to be visualized, as shown below.

S-parameter, dB scale

- I In the Home toolbar, click Add Plot Group and choose ID Plot Group.
- 2 In the Settings window for ID Plot Group, type S-parameter, dB scale in the Label text field.
- 3 Locate the Data section. From the Dataset list, choose Study 3/Solution 3 (sol3).
- 4 Locate the Legend section. Clear the Show legends check box.

Global I

- I Right-click S-parameter, dB scale and choose Global.
- 2 In the Settings window for Global, locate the y-Axis Data section.
- **3** In the table, enter the following settings:

Expression	Unit	Description
es.S22dB	dB	S-parameter, dB, 22-component

